imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

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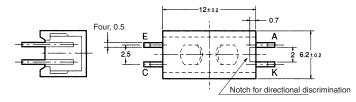
OMRON

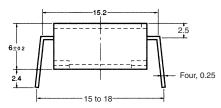
Photomicrosensor (Reflective) **EE-SY113**

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Be sure to read Precautions on page 24.
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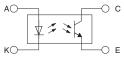
Dimensions

Note: All units are in millimeters unless otherwise indicated.





Internal Circuit



Terminal No.

А

K C E Unless otherwise specified, the tolerances are as shown below.

	Dimensions	Tolerance
	3 mm max.	±0.3
Name Anode	3 < mm ≤ 6	±0.375
	6 < mm ≤ 10	±0.45
Cathode Collector	10 < mm ≤ 18	±0.55
Emitter	18 < mm ≤ 30	±0.65
		1 = 1.90

Features

- Compact reflective Photomicrosensor (EE-SY110) with a molded housing and a dust-tight cover.
- Recommended sensing distance = 4.4 mm

■ Absolute Maximum Ratings (Ta = 25°C)

Item		Symbol	Rated value
Emitter	Forward current	I _F	50 mA (see note 1)
	Pulse forward cur- rent	I _{FP}	1 A (see note 2)
	Reverse voltage	V _R	4 V
Detector	Collector–Emitter voltage	V _{CEO}	30 V
	Emitter–Collector voltage	V _{ECO}	
	Collector current	I _C	20 mA
	Collector dissipa- tion	P _c	100 mW (see note 1)
Ambient tem- perature	Operating	Topr	–40°C to 80°C
	Storage	Tstg	–40°C to 85°C
Soldering temperature		Tsol	260°C (see note 3)

Note: 1. Refer to the temperature rating chart if the ambient temperature exceeds 25°C.

2. The pulse width is 10 μs maximum with a frequency of 100 Hz.

3. Complete soldering within 10 seconds.

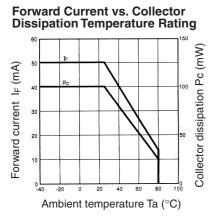
■ Electrical and Optical Characteristics (Ta = 25°C)

Item		Symbol	Value	Condition
Emitter	Forward voltage	V _F	1.2 V typ., 1.5 V max.	I _F = 30 mA
	Reverse current	I _R	0.01 μA typ., 10 μA max.	V _R = 4 V
	Peak emission wavelength	λ _P	940 nm typ.	I _F = 20 mA
Detector	Light current	IL.	160 μA min., 1,600 μA max.	$I_F = 20$ mA, $V_{CE} = 10$ V White paper with a reflection ratio of 90%, d = 4.4 mm (see note)
	Dark current	I _D	2 nA typ., 200 nA max.	V _{CE} = 10 V, 0 ℓx
	Leakage current	I _{LEAK}	2 μA max.	$I_F = 20 \text{ mA}, V_{CE} = 10 \text{ V}$ with no reflection
	Collector–Emitter saturated volt- age	V _{CE} (sat)		
	Peak spectral sensitivity wave- length	λ_P	850 nm typ.	V _{CE} = 10 V
Rising time		tr	30 μs typ.	$V_{CC} = 5 \text{ V}, \text{ R}_{L} = 1 \text{ k}\Omega, \text{ I}_{L} = 1 \text{ mA}$
Falling time		tf	30 μs typ.	$V_{CC} = 5 \text{ V}, \text{ R}_{L} = 1 \text{ k}\Omega, \text{ I}_{L} = 1 \text{ mA}$

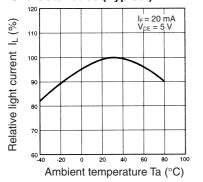
Note: The letter "d" indicates the distance between the top surface of the sensor and the sensing object.

OMROF

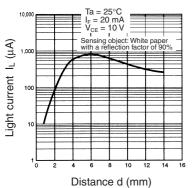
Engineering Data



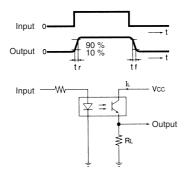
Relative Light Current vs. Ambient Temperature Characteristics (Typical)

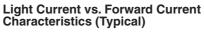


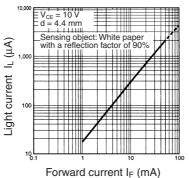
Sensing Distance Characteristics (Typical)



Response Time Measurement Circuit

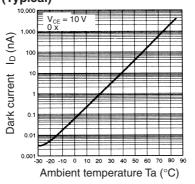




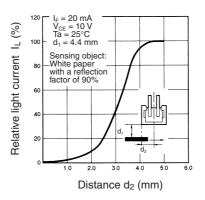


Dark Current vs. Ambient

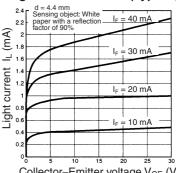
Temperature Characteristics (Typical)



Sensing Position Characteristics (Typical)

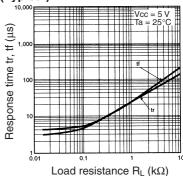


Light Current vs. Collector-Emitter Voltage Characteristics (Typical)



Collector-Emitter voltage V_{CE} (V)

Response Time vs. Load Resistance Characteristics (Typical)



Sensing Angle Characteristics (Typical)

